

Effect of electrochemical etching solution composition on properties of porous SiC film

Cao D.T., Anh C.T., Ha N.T.T., Ha H.T., Huy B., Hoa P.T.M., Duong P.H., Ngan N.T.T., Dai N.X.

Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay Distr., Hanoi, Viet Nam; Institute of Physics, Vietnam Academy of Science and Technology, 10 Dao Tan Street, Ba Dinh Distr., Hanoi, Viet Nam; Delft University of Technology, Mekelweg 4, 2628 CD Delft, Netherlands; College of Science, Vietnam National University - Hanoi, 334 Nguyen Trai Road, Thanh Xuan Distr., Hanoi, Viet Nam

Abstract: Porous amorphous SiC (a-SiC) layer with pore size in the nanometer region was fabricated on the a-SiC/Si substrates by the electrochemical etching method using HF/H₂O/surfactant solution. Systematic study showed that the HF concentration in the etching solution (in the 1-73% region) strongly affects the structure (both the pore size and the pore density) of the porous a-SiC layer. It was also observed the changing of the photoluminescence properties of the porous a-SiC layer when its structure has been changed. ?? 2009 IOP Publishing Ltd.

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Correspondence Address: Cao, D. T.; Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay Distr., Hanoi, Viet Nam; email: dtcao@ims.vast.ac.vn
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Authors with affiliations:

1. Cao, D.T., Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay Distr., Hanoi, Viet Nam
2. Anh, C.T., Institute of Physics, Vietnam Academy of Science and Technology, 10 Dao Tan Street, Ba Dinh Distr., Hanoi, Viet Nam
3. Ha, N.T.T., Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay Distr., Hanoi, Viet Nam
4. Ha, H.T., Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay

Distr., Hanoi, Viet Nam

5. Huy, B., Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay Distr., Hanoi, Viet Nam
6. Hoa, P.T.M., Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay Distr., Hanoi, Viet Nam, Delft University of Technology, Mekelweg 4, 2628 CD Delft, Netherlands
7. Duong, P.H., Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay Distr., Hanoi, Viet Nam
8. Ngan, N.T.T., Institute of Materials Science, Vietnam Academy of Science and Technology, 18 Hoang Quoc Viet Road, Cau Giay Distr., Hanoi, Viet Nam
9. Dai, N.X., College of Science, Vietnam National University - Hanoi, 334 Nguyen Trai Road, Thanh Xuan Distr., Hanoi, Viet Nam

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